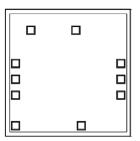
Monolithic Amplifier Die

AVA-24A-D+

50 Ω 5 to 22 GHz

The Big Deal

- Ultra-wideband, 5 to 22 GHz
- Integrated matching, DC blocks, bias circuits
- Unpackaged die form



Product Overview

The AVA-24A-D+ is an ultra-wideband microwave amplifier die fabricated using InGaAs PHEMT technology operating over extremely wide frequency range from 5 to 22 GHz. This model integrates the entire matching network with the majority of the bias circuit, reducing the need for complicated external circuits and simplifying board layouts. These advantages make the AVA-24A-D+ extremely user friendly and enable simple, straightforward use.

Key Features

Feature	Advantages	
Ultra-wideband, 5 to 22 GHz	Very broad frequency range supports a wide array of applications from microwave radio and radar to military communications and countermeasures, among others.	
Excellent gain flatness, ±1.3 dB	Minimizes the need for external equalizer networks and gain flattening components, making it a great fit for instrumentation and EW applications.	
High isolation, 31 to 42 dB	With high reverse isolation (18 – 30 dB directivity), the AVA-24A-D+ is an excellent choice for buffering broadband circuits. It is an ideal LO driver amplifier and provides designers system flexibility and margin when integrating cascaded RF components.	
Single +5V supply	No hassle associated with amplifiers using dual supply such as power supply sequencing Integrated output bias-tee simplifies layout and reduces cost.	
Unpackaged die	Enables the user to integrate the amplifier directly into hybrids.	

Monolithic Amplifier Die

AVA-24A-D+

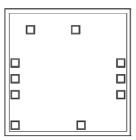
50 Ω 5 to 22 GHz

Product Features

- Gain, 13.1 dB typ. & Flatness, ±1.6 dB
- Output Power, up to +19.4 dBm typ.
- Excellent isolation, 37 dB typ. at 12 GHz
- Single Positive Supply Voltage, 5.0V
- Integrated DC blocks, Bias-Tee & Microwave bypass capacitor
- Unconditionally Stable

Typical Applications

- Military EW and Radar
- DBS
- Wideband Isolation amplifier
- Microwave point-to-point radios
- Satellite systems



+RoHS Compliant
The +Suffix identifies RoHS Compliance. See our web site

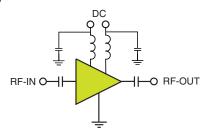
Ordering Information: Refer to Last Page

for RoHS Compliance methodologies and qualifications

General Description

The AVA-24A-D+ is a wideband monolithic amplifier die fabricated using InGaAs PHEMT technology with outstanding gain flatness up to 22 GHz. It is manufactured using PHEMT technology and is unconditionally stable. Its outstanding isolation enables it to be used as a wideband isolation amplifier or buffer amplifier in a variety of microwave systems.

Simplified Schematic and Pad description



Function	Description	
RF-IN RF input pad		
RF-OUT	RF output pad	
DC (V _{D1} , V _{D2}) DC power supply		
GND	Connected to ground	

Note: 1. Bond Pad material - Gold 2. Bottom of Die - Gold plated



Electrical Specifications⁽¹⁾ at 25°C, Zo=50 Ω , (refer to characterization circuit, Fig. 1)

Parameter	Condition (GHz)	Min.	Тур.	Max.	Units
Frequency Range		5.0		22.0	GHz
DC Voltage (V _{D1} , V _{D2})			5.0		V
DC Current (I _{D1} +I _{D2})		94	126	147	mA
	5.0		11.4		
	8.0		13.9		
	10.0		13.4		
Gain	12.0		13.0		dB
	14.0		12.9		
	16.0		13.7		
	22.0		10.6		
	5.0		10.3		
	8.0		32.1		
	10.0		21.1		
Input Return Loss	12.0		18.1		dB
•	14.0		17.6		
	16.0		17.6		
	22.0		8.8		
	5.0		6.4		
	8.0		12.0		
	10.0		10.7		
Output Return Loss	12.0		9.9		dB
Catpat Hotalii 2000	14.0		10.0		"-
	16.0		10.4		
	22.0		15.9		
	5.0		32.6		
	8.0		27.5		
	10.0		26.4		
Output IP3 (2)	12.0		25.3		dBm
Catpat II C	14.0		24.2		d d d d
	16.0		23.3		
	22.0		24.4		
	5.0	1	16.9		1
	8.0		18.4		
	10.0		19.0		
Output Power @ 1 dB compression	12.0		19.2		dBm
Output I ower & I ab compression	14.0		19.4		dbiii
	16.0		19.2		
	22.0		16.7		
	5.0		9.3		
	8.0		5.2		
	10.0		5.4		
Noise Figure	12.0		5.4		dB
Noise i lyule	1		1		ub
	14.0		5.8		
	16.0		6.1		
Dina akirika (Ia alakira Oaia)	22.0	1	6.4		-ID
Directivity (Isolation-Gain)	12	-	24		dB
DC Current Variation vs. Voltage		-	0.002		mA/mV
Thermal Resistance			45		°C/W

Absolute Maximum Ratings(3)

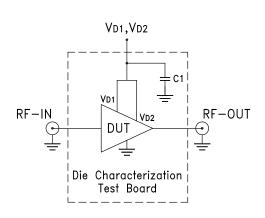
Parameter	Ratings	
Operating Temperature	-40°C to 85°C	
Channel Temperature	150°C	
DC Voltage V _{D1} , V _{D2} Pad ⁽⁴⁾	5.5 V	
DC Voltage RF-IN &RF OUT	10 V	
Power Dissipation	860 mW	
DC Current V _{D1} & V _{D2} (Total)	160 mA	
Input Power (CW)	20 dBm	



Input Fower (CW)

1. Measured on Mini-Circuits Die Characterization test board
See Characterization Test Circuit (Fig. 1)

2. At Pout=8 dBm/tone
3. Permanent damage may occur if any of these limits are exceeded.
These maximum ratings are not intended for continuous normal operation.
Measured in industry standard 3x3 min 8-lead MCLP package
4. For continuous operation do not exceed 5.2V



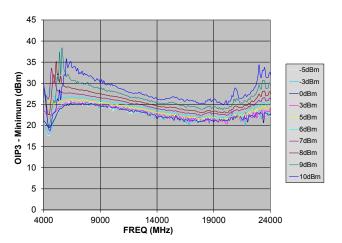


Figure 1: Test Circuit used for characterization. Gain, Return loss, Output power at 1dB compression (P1 dB), output IP3 (OIP3) and noise figure measured using Agilent's N5242A PNA-X microwave network analyzer. C1=100 pF, Compex capacitor CSA-200-10X10X10X5-G-101-M

Conditions:

- 1. Gain and Return loss: Pin= -25dBm
- 2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, 8 dBm/tone at output.

Die Layout

Ground Pad Ground Pad RF-IN Bonding Pad Ground Pad Ground Pad Ground Pad Ground Pad Ground Pad Ground Pad

Fig 2. Die Layout

Bonding Pad Position

(Dimensions in µm, Typical)

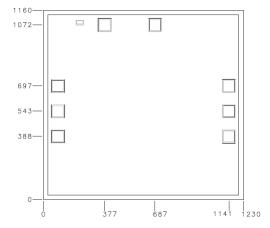


Fig 3. Bonding Pad Positions

Critical Dimensions

Parameter	Values
Die Thickness, μm	100
Die Width, µm	1230
Die Length, µm	1160
Bond Pad Size, µm	80 x 80

Assembly and Handling Procedure

1. Storage

Dice should be stored in a dry nitrogen purged desiccators or equivalent.

2. ESD

MMIC PHEMT amplifier dice are susceptible to electrostatic and mechanical damage. Die are supplied in antistatic protected material, which should be opened in clean room conditions at an appropriately grounded anti-static worksta tion. Devices need careful handling using correctly designed collets, vacuum pickup tips or sharp antistatic tweezers to deter ESD damage to dice.

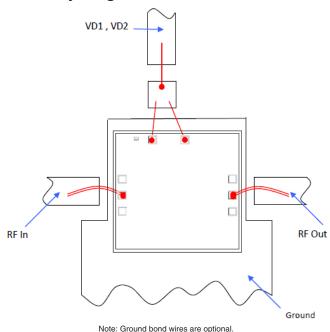
3. Die Attach

The die mounting surface must be clean and flat. Using conductive silver filled epoxy, recommended epoxies are DieMat DM6030HK-PT/H579 or Ablestik 84-1LMISR4. Apply sufficient epoxy to meet required epoxy bond line thickness, epoxy fillet height and epoxy coverage around total die periphery. Parts shall be cured in a nitrogen filled atmosphere per manufacturer's cure condition. It is recommended to use antistatic die pick up tools only.

Wire Bonding

Bond pad openings in the surface passivation above the bond pads are provided to allow wire bonding to the dice gold bond pads. Thermosonic bonding is used with minimized ultrasonic content. Bond force, time, ultrasonic power and temperature are all critical parameters. Suggested wire is pure gold, 1 mil diameter. Bonds must be made from the bond pads on the die to the package or substrate. All bond wires should be kept as short as low as reasonable to minimize performance degradation due to undesirable series inductance.

Assembly Diagram



Recommended Wire Length, Typical

Wire	Wire Length (mm)	Wire Loop Height (mm)
RF-In, RF-Out	0.25	0.15
VD1, VD2	0.50	0.15

PCB Information

PCB material	Rogers 435013
Dielectric thickness	10 mil
Copper thickness (Top & Bottom)	0.5 oz.
Finish	ENIG



Additional Detailed Technical Information additional information is available on our dash board.				
	Data Table			
Performance Data	Swept Graphs			
	S-Parameter (S2P Files) Data Set with and without port extension(.zip file)			
Case Style	Die			
	Quantity, Package	Model No.		
Die Ordering and packaging information	Small, Gel - Pak: 10,50,100 KGD* Medium [†] , Partial wafer: KGD*<1190 Large [†] , Full Wafer	AVA-24A-DG+ AVA-24A-DP+ AVA-24A-DF+		
	†Available upon request contact sales representative Refer to AN-60-067			
Environmental Ratings	ENV-80			

^{*}Known Good Dice ("KGD") means that the dice in question have been subjected to Mini-Circuits DC test performance criteria and measurement instructions and that the parametric data of such dice fall within a predefined range. While DC testing is not definitive, it does help to provide a higher degree of confidence that dice are capable of meeting typical RF electrical parameters specified by Mini-Circuits.

ESD Rating**

Human Body Model (HBM): Class 1A (250 to <500V) in accordance with ANSI/ESD STM 5.1 - 2001

Additional Notes

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^{**} Tested in industry standard 3x3 mm 8-lead MCLP package.